## NSN 5962-01-076-8397

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-076-8397

Body Length:	
0.440 inches	
Body Width:	
Between 0.248 ind	ches and 0.325 inches
Body Height:	
0.085 inches	
Maximum Power	Dissipation Rating:
910.0 milliwatts	
Operating Temp	urature Range:
-55.0/+125.0 degr	ees celsius
Storage Tempura	ature Range:
-65.0/+150.0 degr	ees celsius
Features Provide	ed:
Hermetically seale	ed and monolithic and positive outputs and w/storage and programmable and programmed and bipolar and 3-state output
and schottky and	high speed and expandable and w/buffered output and w/decoded output and w/enable and w/disable
Inclosure Materia	al:
Ceramic and glass	S
Inclosure Config	uration:
Flat pack	
Output Logic For	rm:
Transistor-transist	tor logic
Input Circuit Patt	tern:
6 input	
Terminal Surface	e Treatment:
Solder	
Voltage Rating A	nd Type Per Characteristic:
5.5 volts power se	ource
Time Rating Per	Chacteristic:
40.00 nanosecono	ds propagation delay time, low to high level output and 84.00 nanoseconds propagation delay time, high to low level
output	
Memory Device	Гуре:
Rom	
Memory Capacity	y:
Unknown	
Test Data Docum	nent:
82577-932821 sta	indard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type A	
16 flat leads	
Shelf Life:	
N/a	
Unit Of Measure:	

Yes - demil/mli

## NSN 5962-01-076-8397

Memory Microcircuit - Page 2 of 2

**Fiig:** A458a0

